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Non-Ideal Effects and other Performance Parameters; III-9. New

Transistors; Glossary for End-of-Chapter Review; References; Exercises for Chapter III; Chapter IV. OPTICAL PROPERTIES OF SOLIDS; IV-1.

Introduction. IV-2. Review of the Properties of Light; IV-3. The Absorption Process; IV-4. The Emission Process; IV-5. Imagers; IV-6. Displays; IV-7. Power Generation; IV-8. Optical Signal Transmission Media; Glossary; References; Exercises for Chapter IV Chapter V. MAGNETIC AND SUPERCONDUCTING PROPERTIES OF SOLIDSV-1. Introduction; V-2. Magnetic Properties of Solids; V-3. Sources of Magnetization; V-4. Magnetic Anisotropy and Invar Alloys; V-5. Amorphous Magnetic Materials; V-6. Soft Magnets and Hard Magnets; V-7. Magnetic Devices and Applications; V-8. Properties of Superconductors; V-9. Applications of Superconductors; V-10. Superconducting Materials; Glossary for End-of-Chapter Review; References; Exercises for Chapter V; Chapter VI. MICROMACHINES, SENSORS AND PACKAGING MATERIALS; VI-1. Introduction. VI-2. Micromachining

## Sommario/riassunto

The electronic properties of solids have become of increasing importance in the age of information technology. The study of solids and materials, while having originated from the disciplines of physics and chemistry, has evolved independently over the past few decades. The classical treatment of solid-state physics, which emphasized classifications, theories and fundamental physical principles, is no longer able to bridge the gap between materials advances and applications. In particular, the more recent developments in device physics and technology have not necessarily been driven by new conc